

Flange Mount Termination 200 Watts, 50Ω



<u>Description</u>

The G200N50W4 is high performance Aluminum Nitride (AIN) flange mount termination intended as a cost competitive alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators and for use in power combiners. The termination is also RoHS compliant!

Features:

- RoHS Compliant
- 200 Watts
- DC 2.2 GHz
- AIN Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

General Specifications

Resistive Element Thick Film
Substrate AIN Ceramic

Mounting Flange Nickel Plated Copper

Operating Temperature -50 to +150°C (see de rating chart)

Tolerance is ± 0.010 ", unless otherwise specified. Designed to meet of exceed applicable portions of MIL-E-5400. **All dimensions in inches**.

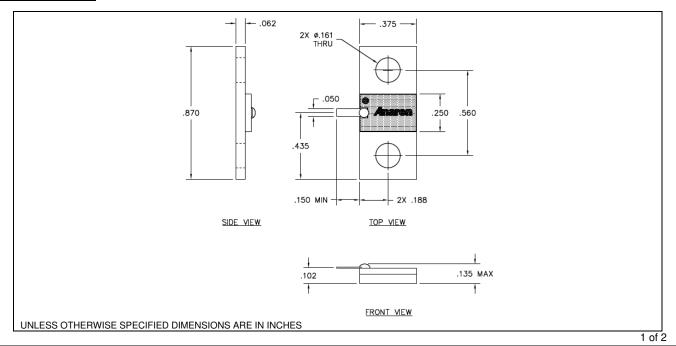
Electrical Specifications

Resistance Value:50 Ohms, \pm 2%Power:200 WattsFrequency Range:DC - 2.2 GHz

Return Loss > 20 dB from DC to 2.2 GHz

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.**

Outline Drawing

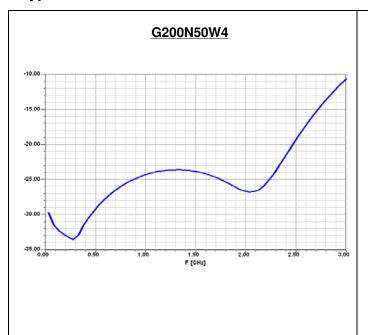


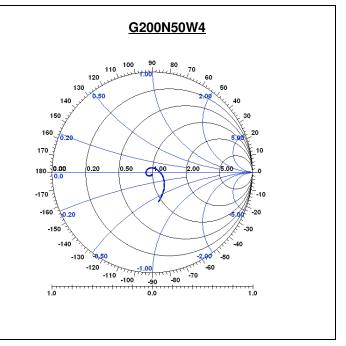


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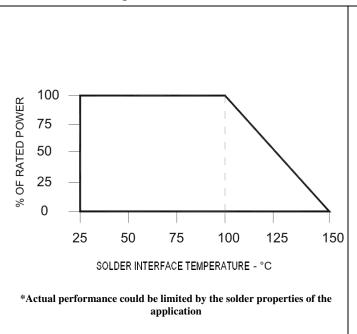


Typical Performance:

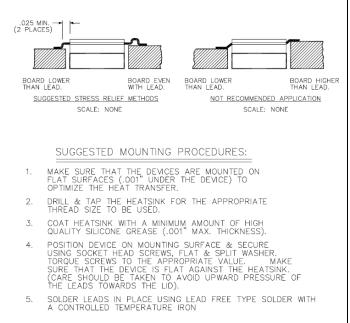




Power De-rating:



Mounting Footprint and Procedure:



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